Honeywell's Docket No. 30-4790 (4780) Practitioner's Docket No. 100595.0048-US3





## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

WASHINGTON, D.C. 20231

Inventor:

Zhang et al.

Serial No: 09/357264

Filed:

July 19, 1999

For:

Comp. for Chemical Mechanical

Planarization of Copper,

**Tantalum and Tantalum Nitride** 

Examiner: Brown, Charlotte A.

Art Unit:

1765

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## RESPONSE TO OFFICE ACTION

The Honorable Commissioner of Patents and Trademarks Washington, D.C. 20231

Dear Sir:

This paper responds to the Office Action dated February 20, 2002. Please enter the following (Clean Copy of Amended Claims follows with non-amended claims in italics for your immediate reference. A Marked Up Copy of the Amended Claims and a full Clean Copy of the Claims to be entered are attached hereto):

## IN THE CLAIMS

- 1. A chemical mechanical planarization system that includes a Cu/Ta/TaN surface, a singleslurry solution comprising:
  - a) an oxidizing reactant selected from the group consisting of  $H_2O_2$ ,  $HNO_3$  and mixtures thereof; and
  - b) a co-reactant is selected from the group consisting of  $H_3PO_4$ ,  $H_2SO_4$ ,  $HNO_3$ , oxalic acid, acetic acid, organic acids and mixtures thereof.